

PARA LIGHT ELECTRONICS CO., LTD.

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DATA SHEET

PART NO.: L-C195JRLBCT-U1

REV: <u>A / 5</u>

CUSTOMER'S APPROVAL: DRAWING NO.: DS-78-14-0003

DCC:

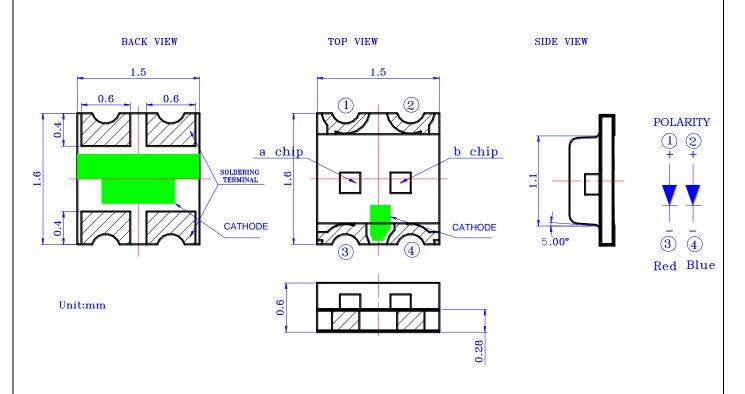
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PACKAGE OUTLINE DIMENSIONS



Notes:

1. a chip: Red; b chip: Blue

- 2. All dimensions are in millimeters.
- 3. Tolerance is \pm 0.1mm (.004") unless otherwise noted.

Features

- * Dual color, top view, wide view angle Chip LED.
- * Package in 8mm tape on 7" diameter reels.
- * Compatible with automatic Pick & Place equipment.
- * Compatible with Reflow soldering and Wave soldering processes.
- * EIA STD package.
- \ast I.C. compatible.
- * Pb free product.
- * Moisture sensitivity level: 3

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• Chip Materials

Chip	Light Color	Dice Material	Lens Color
a	JR: Red	AlInGap	Watan Claan
b	LB: Blue	InGaN	Water Clear

• Absolute Maximum Ratings (Ta=25°C)

Symbol	Parameter	Ratin	Unit		
Symbol	Farameter	Blue	Red	Unit	
PD	Power Dissipation	80	75	mW	
Ipf	Peak Forward Current	80	80	mA	
IPF	(1/10 Duty Cycle, 0.1ms Pulse Width)	80			
IF	Continuous Forward Current	25	30	mA	
VR	Reverse Voltage	5	5	V	
ESD	Electrostatic Discharge Threshold (HBM) ^{Note A}	1000	2000	V	
Topr	Operating Temperature Range	-40 ~ +85		°C	
Tstg	Storage Temperature Range	-40 ~ +85		°C	

Note A:

HBM: Human Body Model. Seller gives no other assurances regarding the ability of to withstand ESD.

• Electro-Optical Characteristics (Ta=25°C)

Parameter	Symbol	Red	Blue	Unit	Test Condit on	
	Min.		28	71	mcd	IF=20mA
Luminous Intensity	Тур.	IV	40	140		
	Max.		112	280		
Viewing Angle	Тур.	2 θ 1/2	130		deg	Note 2
	Min.	λd	625	465	nm	IF=20mA
Dominant Wavelength	Тур.		631	470		
	Max.		635	475		
Spectral Line Half-Width	Тур.	Δλ	17	25	nm	
	Min.		1.7	2.8	V	IF =20mA
Forward Voltage	Тур.	VF	2.0	3.0		
	Max.		2.4	3.4		
Reverse Current Max.		IR	10	50	μA	VR = 5V
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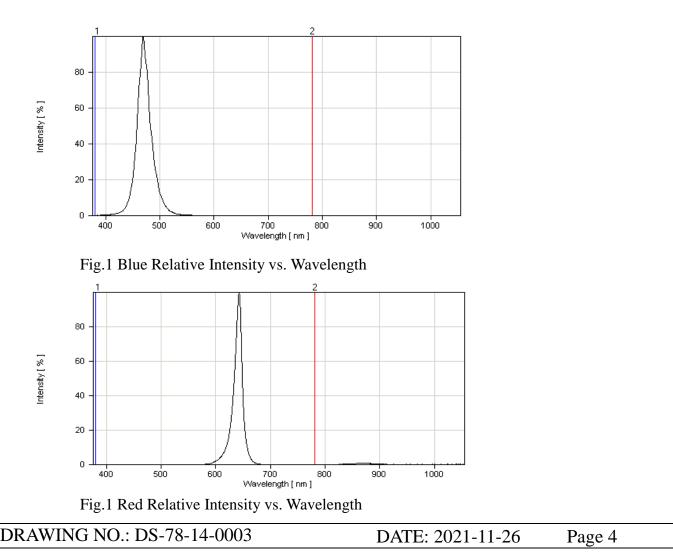
Notes:

- 1. Luminous intensity is measured with a light sensor and filter combination that proximities the CIE eye-response curve.
- 2. θ 1/2 is the off-axis angle at which the luminous intensity is half the axial luminous intensity.
- 3. The dominant wavelength λ d is derived from the CIE chromaticity diagram and represents the single wavelength which defines the color of the device.
- 4. Caution in ESD:

Static Electricity and surge damages the LED. It is recommended use a wrist band or anti-electrostatic glove when handling the LED. All devices, equipment and machinery must be properly grounded.

5. Major standard testing equipment by "Instrument System" Model: CAS140B Compact Array Spectrometer and "KEITHLEY" Source Meter Model: 2400.

• Typical Electro-Optical Characteristics Curves





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• Red Typical Electro-Optical Characteristics Curves

(25°CAmbient Temperature Unless Otherwise Noted)

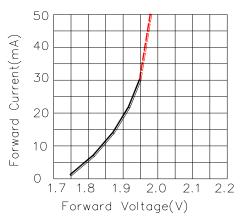


Fig.2 Forward Current vs.Forward Voltage

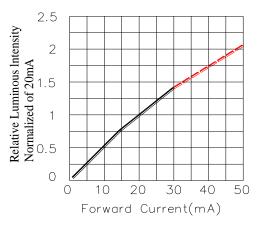
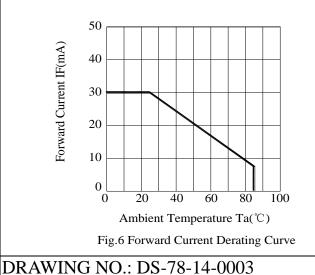


Fig.4 Relative Luminous Intensity vs.Forward Current



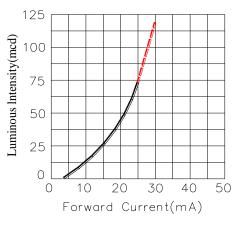


Fig.3 Luminous Intensity vs.Forward Current

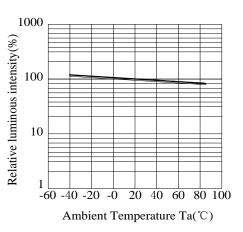
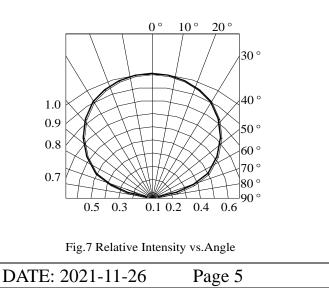


Fig.5 Luminous Intensity vs.Ambient Temperature





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Blue Typical Electro-Optical Characteristics Curves

(25°CAmbient Temperature Unless Otherwise Noted)

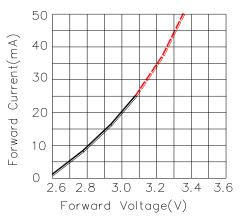


Fig.2 Forward Current vs.Forward Voltage

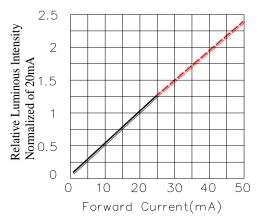
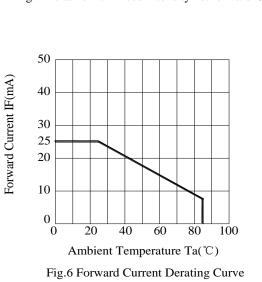


Fig.4 Relative Luminous Intensity vs.Forward Current



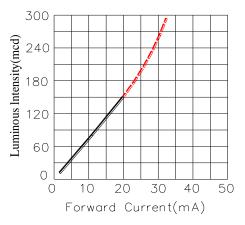


Fig.3 Luminous Intensity vs.Forward Current

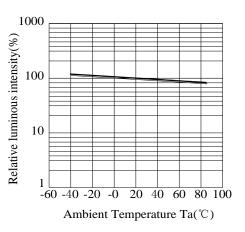
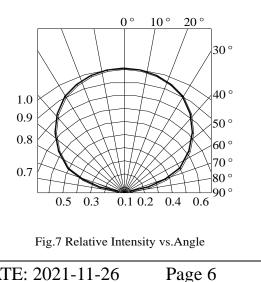


Fig.5 Luminous Intensity vs.Ambient Temperature



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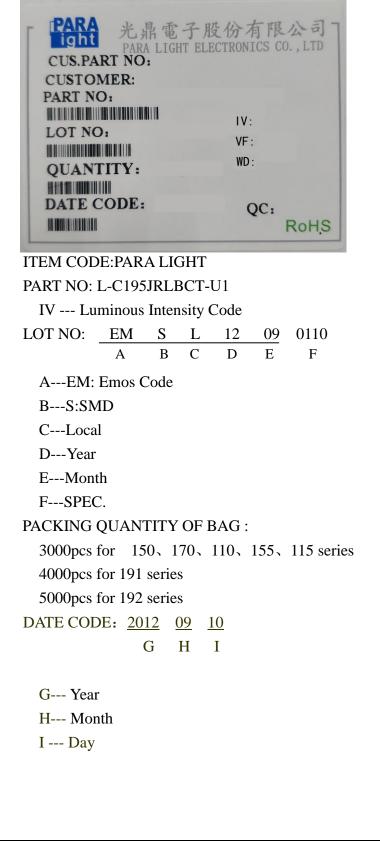
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Label Explanation •



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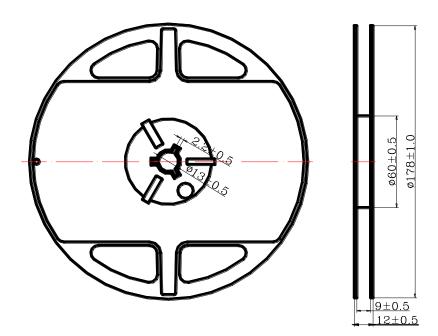
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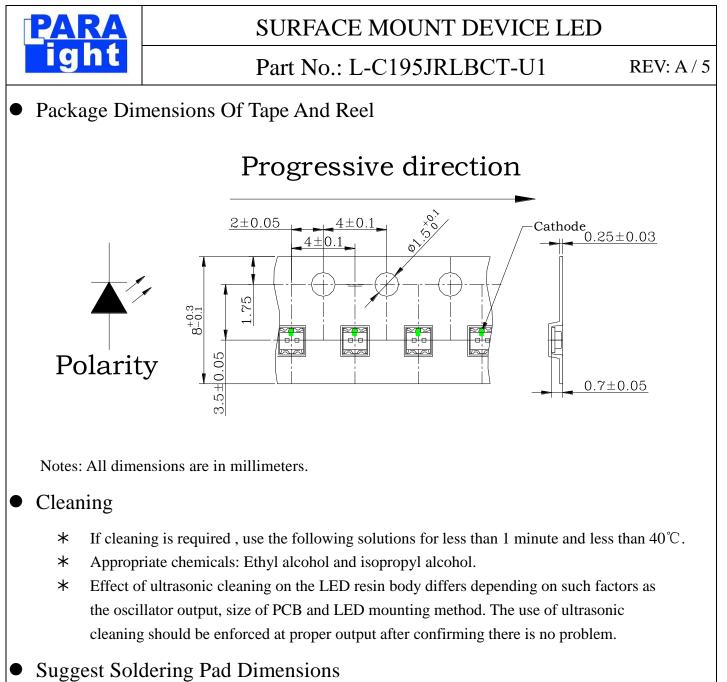
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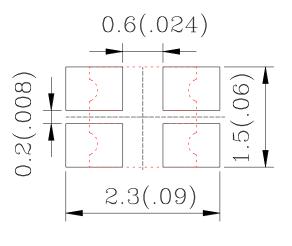
• Reel Dimensions



Notes:

- 1. Taping Quantity: 3000pcs
- 2. The tolerances unless mentioned is $\pm 0.1 \text{mm}$, Angle $\pm 0.5^\circ\,$, Unit: mm.





Direction of PWB camber and go to reflow furnace

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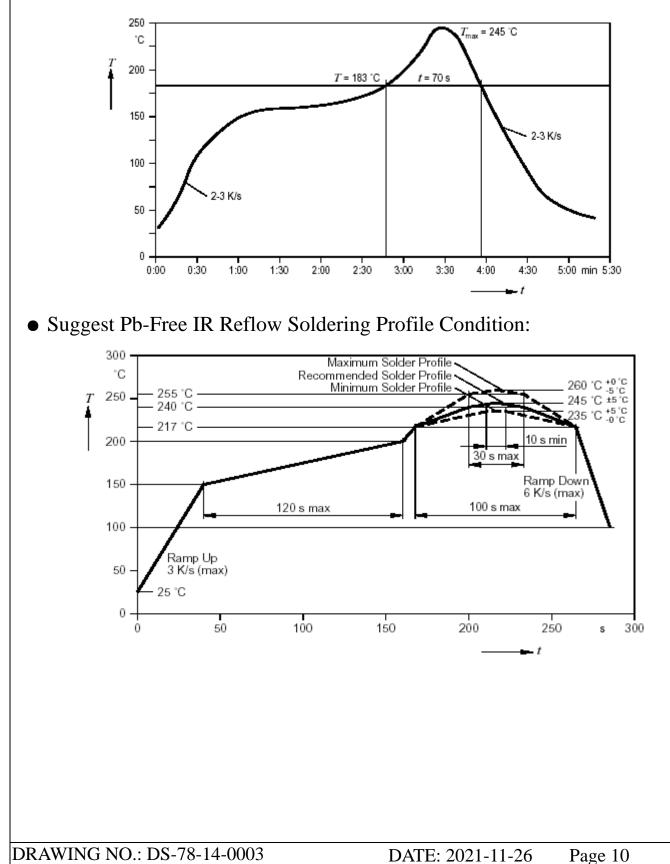
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• Suggest Sn/Pb IR Reflow Soldering Profile Condition:





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Bin Code List

	Lumir	ous Intensity (IV), Unit: r	ncd@2	0mA		
Red (a chip)				Blue (b chip)			
Bin Code	Min	Max	Bin C	ode	Min	Max	
Ν	28	45	Q		71	112	
Р	45	71	R		112	180	
Q	71	112	S		180	280	
Tolerance of each bin are $\pm 15\%$							
	For	ward Voltage(V	F), Unit:V	@20mA	A		
		Blue (b chip)				
	Bin Co	ode N	lin	Max			
	K8	2	.8	2.95			
	K9	2.	95	3.1	10		
	K10	3.	10	3.2	25		
	K11	3.	25 3.40		40		
	То	lerance of eacl	h bin are ± 0	0.1Volt			
	Dominant Wavelength (Hue), Unit: nm@20mA						
	Bin Code	Ν	<i>/</i> lin	n Max			
	AC	4	65	470			
	AD	4	70 475		475		
	Г	Tolerance of ea	h hin are +	- 1 n m			

Tolerance of each bin are ± 1 nm

CAUTIONS

1.Application Limitation:

The LED's described here are intended to be used for ordinary electronic equipment (such as office equipment, communication equipment and household application). Consult PARA's sales in advance for information on application in which exceptional quality and reliability are required, particularly when the failure or malfunction of the LED's may directly jeopardize life or health (such as airplanes, automobiles, traffic control equipment, life support system and safety devices).

2.Storage:

Do not open moisture proof bag before the products are ready to use.

Before opening the package: The LEDs should be kept at 30° C or less and 90° RH or less.

If the moisture absorbent material (silica gel) has faded away or the LEDs have exceeded the storage time, baking treatment should be performed using the following conditions.

Baking treatment: $60\pm5^{\circ}$ C for 24 hours

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3.Soldering

Do not apply any stress to the lead frame during soldering while the LED is at high temperature. Recommended soldering condition. **Reflow Soldering:** Pre-heat 120~150 °C, 120sec. MAX., Peak temperature : 240 °C Max. Soldering time: 10 sec Max. Soldering Iron: (Not recommended) Temperature 300 ℃ Max., Soldering time : 3 sec. Max.(one time only), power dissipation of iron : 20W Max. use SN60 solder of solder with silver content and don't to touch LED lens when soldering. Wave soldering: Pre-heat 100 °C Max, Pre-heat time 60 sec. Max, Solder wave 260 °C Max, Soldering time 5 sec. Max. preformed consecutively cooling process is required between 1st and 2nd soldering processes. 4. Lead-Free Soldering For Reflow Soldering: 1、Pre-Heat Temp:150-180°C,120sec.Max. 2. Soldering Temp: Temperature Of Soldering Pot Over 230°C,40sec.Max. 3、Peak Temperature:260°C, 5sec. 4. Reflow Repetition:2 Times Max. 5. Suggest Solder Paste Formula 93.3 Sn/3.1 Ag/3.1 Bi /0.5 Cu For Soldering Iron (Not Recommended): 1、 Iron Tip Temp:350°C Max. 2. Soldering Iron:30w Max. 3、Soldering Time: 3 Sec. Max. One Time. For Dip Soldering: 1、Pre-Heat Temp:150°C Max. 120 Sec. Max. 2、Bath Temp:265°C Max. 3. Dip Time:5 Sec. Max. 5. Drive Method Circuit model B Circuit model A (A)Recommended circuit. (B)The difference of brightness between LED's could be found due to the Vf-If characteristics of LED.